F-band, High-Efficiency GaN Power Amplifier for the Scanning Microwave Limb Sounder and SOFIA, Phase II



Completed Technology Project (2014 - 2017)

Project Introduction

QuinStar Technology proposes to develop a high-efficiency, 4-W SSPA operating at F-band frequencies (106-114 GHz). This will be achieved by employing two major innovations. Firstly, we are employing state-of-the-art wide bandgap GaN (Gallium Nitride) devices. At millimeter-wave frequencies, these GaN devices have demonstrated power densities of 5 to 8 times higher than GaAs or InP devices. Further, we are proposing to operate these devices in a quasi-switching mode, which has demonstrated, in Phase I simulations, drain efficiencies approaching 70%. The resulting MMIC, operating over the 106 to 114 GHz band, will produce an output power of one watt and an efficiency of greater than 33%. Secondly, we are proposing to utilize a new low loss, H-tee combining approach to combine 4 of these high-efficiency chips to achieve 4 watts. The net result is a unique combination of high performance devices and innovative power combining. We anticipate that this work will result in an order of magnitude increase in the state-of-the-art of SSPA output power and efficiency at F-band. We anticipate that this work will be very important for NASA's Earth Science missions and for DoD W-band radar and communications applications.

Primary U.S. Work Locations and Key Partners





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Small Business Innovation Research/Small Business Tech Transfer

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Organizations Performing Work	Role	Туре	Location
Quinstar Technology, Inc	Lead Organization	Industry Small Disadvantaged Business (SDB)	Torrance, California
Jet Propulsion Laboratory(JPL)	Supporting Organization	NASA Center	Pasadena, California

Primary U.S. Work Locations

California

Project Transitions

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April 2014: Project Start



December 2017: Closed out

Closeout Documentation:

• Final Summary Chart(https://techport.nasa.gov/file/137595)

Images



F-band, High-Efficiency GaN Power Amplifier for the Scanning Microwave Limb Sounder and

SOFIA, Phase II (https://techport.nasa.gov/imag e/132107)

Responsible Mission

Organizational

Responsible Mission Directorate:

Space Technology Mission Directorate (STMD)

Lead Organization:

Quinstar Technology, Inc

Responsible Program:

Small Business Innovation Research/Small Business Tech Transfer

Project Management

Program Director:

Jason L Kessler

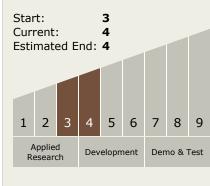
Program Manager:

Carlos Torrez

Principal Investigator:

Edmar Camargo

Technology Maturity (TRL)





Small Business Innovation Research/Small Business Tech Transfer

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Completed Technology Project (2014 - 2017)

Technology Areas

Primary:

- TX08 Sensors and Instruments
 - ☐ TX08.1 Remote Sensing Instruments/Sensors
 - ☐ TX08.1.4 Microwave, Millimeter-, and Submillimeter-Waves

Target Destinations

The Sun, Earth, The Moon, Mars, Others Inside the Solar System, Outside the Solar System

